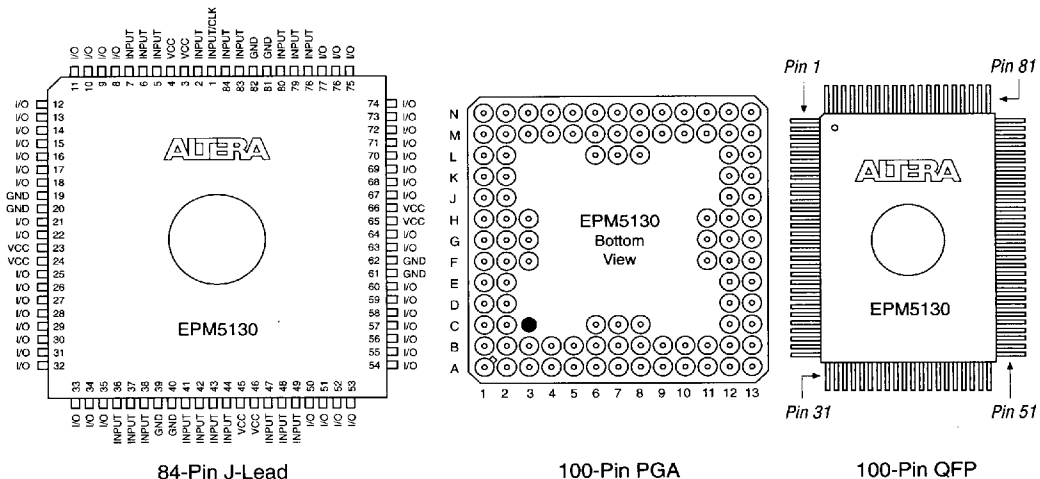


Features

- High-density, 128-macrocell, general-purpose MAX 5000 EPLD
- 128 macrocells optimized for pin-intensive applications, easily integrating over 60 TTL MSI and SSI components
- High-speed multi-LAB architecture
 - t_{PD} as fast as 15 ns
 - Counter frequencies up to 83.3 MHz
 - Pipelined data rates up to 100 MHz
- High pin count for 16- or 32-bit data paths
- 256 shareable expander product terms ("expanders") allowing over 32 product terms in a single macrocell
- 20 high-speed dedicated inputs for fast latching of 16-bit functions
- Fast Clock-to-output delays for bus-oriented functions
- Programmable I/O architecture with up to 84 inputs or 64 outputs in 100-pin packages, or up to 68 inputs or 48 outputs in 84-pin packages
- Available in windowed ceramic and one-time-programmable (OTP) packages (see Figure 17):
 - 84-pin J-lead chip carrier (JLCC and PLCC)
 - 100-pin pin-grid array (ceramic PGA only)
 - 100-pin quad flat pack (CQFP and PQFP)
- Military devices available. For information, refer to the *Military Products Data Sheet* in this data book.

Figure 17. EPM5130 Package Pin-Out Diagrams

Package outlines not drawn to scale. See Tables 6 and 7 in this data sheet for pin-out information. Windows in ceramic packages only.



General Description

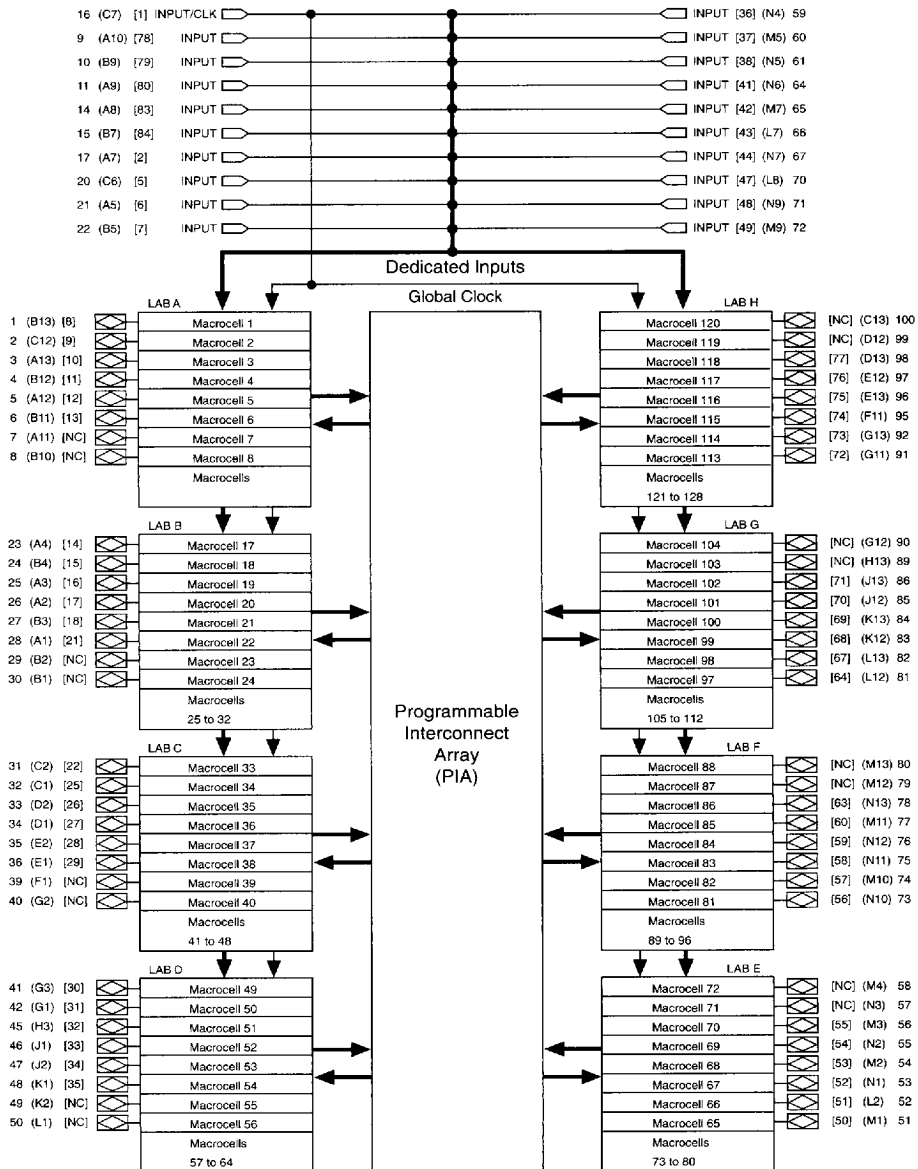
Altera EPM5130 EPLDs are user-configurable, high-performance MAX 5000 EPLDs optimized for pin-intensive designs. They provide high-density replacements for 74-series SSI, MSI TTL, and CMOS logic. These EPLDs can quickly integrate multiple 20- and 24-pin low-density PLDs and high-pin-count subsystems, such as custom DMA controllers. In addition, they can handle a 32-bit data path application with enough I/O to implement the required control signals.

The EPM5130 consists of 128 macrocells equally divided into 8 Logic Array Blocks (LABs), each containing 16 macrocells and 32 expander product terms. Expander product terms can be used and shared by all macrocells in the device to ensure efficient use of device resources. Because the LAB is very compact, the high speeds required by most I/O subsystems are maintained. See Figure 18.

The EPM5130 has 20 dedicated input pins that allow high-speed input latching of 16-bit functions. One of these inputs can be configured as a global Clock to provide enhanced Clock-to-output delays for bus-oriented functions. They also have 64 I/O pins, 8 in each LAB, that can be configured for input, output, or bidirectional operation. Dual feedback on the I/O pins provides the most efficient use of device pin resources.

Figure 18. EPM5130 Block Diagram

Numbers without parentheses are for QFP packages; numbers in parentheses are for PGA packages; numbers in brackets are for J-lead packages.

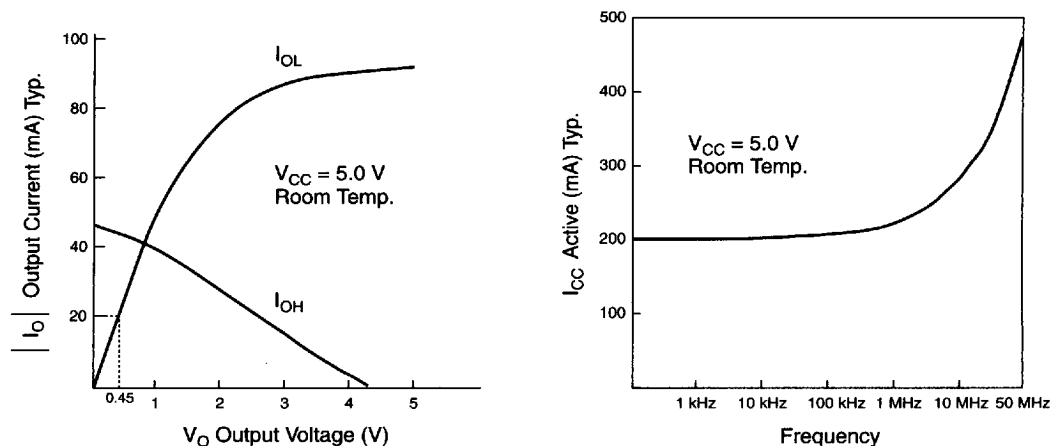


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MAX 5000

Figure 19 shows the output drive characteristics of EPM5130 I/O pins and typical supply current (I_{CC}) versus frequency.

Figure 19. Typical Output Drive Characteristics & I_{CC} vs. Frequency



Absolute Maximum Ratings See *Operating Requirements for Altera Devices* in this data book.

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CC}	Supply voltage	With respect to GND	-2.0	7.0	V
V_I	DC input voltage	Note (1)	-2.0	7.0	V
I_{MAX}	DC V_{CC} or GND current			500	mA
I_{OUT}	DC output current, per pin		-25	25	mA
P_D	Power dissipation			2500	mW
T_{STG}	Storage temperature	No bias	-65	150	°C
T_{AMB}	Ambient temperature	Under bias, Note (2)	-65 [-55]	135 [125]	°C
T_J	Junction temperature	Under bias, Note (2)		150 [175]	°C

Recommended Operating Conditions

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CC}	Supply voltage	Notes (3), (4)	4.75 (4.5)	5.25 (5.5)	V
V_I	Input voltage		0	V_{CC}	V
V_O	Output voltage		0	V_{CC}	V
T_A	Operating temperature	For commercial use	0	70	°C
T_A	Operating temperature	For industrial use	-40	85	°C
T_C	Case temperature	For military use	-55	125	°C
t_R	Input rise time			100	ns
t_F	Input fall time			100	ns

DC Operating Conditions Notes (5), (6)

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V_{IH}	High-level input voltage	Note (2)	2.0 [2.2]		$V_{CC} + 0.3$	V
V_{IL}	Low-level input voltage		-0.3		0.8	V
V_{OH}	High-level TTL output voltage	$I_{OH} = -4$ mA DC	2.4			V
V_{OL}	Low-level output voltage	$I_{OL} = 8$ mA DC			0.45	V
I_I	Input leakage current	$V_I = V_{CC}$ or GND	-10		10	μA
I_{OZ}	Tri-state output off-state current	$V_O = V_{CC}$ or GND	-40		40	μA
I_{CC1}	V_{CC} supply current (standby)	$V_I = V_{CC}$ or GND, Notes (3), (7)		175	250 (325)	mA
I_{CC3}	V_{CC} supply current (active)	$V_I = V_{CC}$ or GND, No load, $f = 1.0$ MHz, Notes (3), (7)		180	275 (375)	mA

Capacitance

Symbol	Parameter	Conditions	Min	Max	Unit
C_{IN}	Input pin capacitance	$V_{IN} = 0$ V, $f = 1.0$ MHz		10	pF
C_{IO}	I/O pin capacitance	$V_{OUT} = 0$ V, $f = 1.0$ MHz		20	pF

AC Operating Conditions *Note (6)*

External Timing Parameters			EPM5130A-15		EPM5130A-20		
Symbol	Parameter	Conditions	Min	Max	Min	Max	Unit
t_{PD1}	Input to non-registered output	$C1 = 35 \text{ pF}$		15		20	ns
t_{PD2}	I/O input to non-registered output	$C1 = 35 \text{ pF}$		25		33	ns
t_{SU}	Global clock setup time		10		13		ns
t_H	Global clock hold time		0		0		ns
t_{CO1}	Global clock to output delay	$C1 = 35 \text{ pF}$		8		9	ns
t_{CH}	Global clock high time		5		7		ns
t_{CL}	Global clock low time		5		7		ns
t_{ASU}	Array clock setup time		5		6		ns
t_{AH}	Array clock hold time		5		6		ns
t_{ACO1}	Array clock to output delay	$C1 = 35 \text{ pF}$		15		20	ns
t_{ACH}	Array clock high time	<i>Note (8)</i>	5		7		ns
t_{ACL}	Array clock low time	<i>Note (5)</i>	5		7		ns
t_{CNT}	Minimum global clock period			12		15	ns
f_{CNT}	Max. internal global clock frequency	<i>Note (7)</i>	83.3		66.7		MHz
t_{ACNT}	Minimum array clock period			12		15	ns
f_{ACNT}	Max. internal array clock frequency	<i>Note (7)</i>	83.3		66.7		MHz
f_{MAX}	Maximum clock frequency	<i>Note (9)</i>	100.0		71.4		MHz

Internal Timing Parameters <i>Note (10)</i>			EPM5130A-15		EPM5130A-20		
Symbol	Parameter	Conditions	Min	Max	Min	Max	Unit
t_{IN}	Input pad and buffer delay			3		4	ns
t_{IO}	I/O input pad and buffer delay			3		4	ns
t_{SEXP}	Expander array delay			8		10	ns
t_{LAD}	Logic array delay			8		12	ns
t_{LAC}	Logic control array delay			5		5	ns
t_{OD}	Output buffer and pad delay	$C1 = 35 \text{ pF}$		3		3	ns
t_{ZX}	Output buffer enable delay	$C1 = 35 \text{ pF}$		5		5	ns
t_{XZ}	Output buffer disable delay	$C1 = 5 \text{ pF}$		5		5	ns
t_{SU}	Register setup time		2		1		ns
t_{LATCH}	Flow-through latch delay			1		1	ns
t_{RD}	Register delay			1		1	ns
t_{COMB}	Combinatorial delay			1		1	ns
t_H	Register hold time		7		10		ns
t_{IC}	Array clock delay			6		8	ns
t_{ICS}	Global clock delay			0		0	ns
t_{FD}	Feedback delay			1		1	ns
t_{PRE}	Register preset time			3		3	ns
t_{CLR}	Register clear time			3		3	ns
t_{PIA}	Prog. Interconnect Array delay			10		13	ns

AC Operating Conditions Note (6)

External Timing Parameters			EPM5130-1		EPM5130-2		EPM5130		
Symbol	Parameter	Conditions	Min	Max	Min	Max	Min	Max	Unit
t_{PD1}	Input to non-registered output	$C1 = 35 \text{ pF}$		25		30		35	ns
t_{PD2}	I/O input to non-registered output	$C1 = 35 \text{ pF}$		40		45		55	ns
t_{SU}	Global clock setup time		15		20		25		ns
t_H	Global clock hold time		0		0		0		ns
t_{CO1}	Global clock to output delay	$C1 = 35 \text{ pF}$		14		16		20	ns
t_{CH}	Global clock high time		8		10		12.5		ns
t_{CL}	Global clock low time		8		10		12.5		ns
t_{ASU}	Array clock setup time		5		6		10		ns
t_{AH}	Array clock hold time		6		8		10		ns
t_{ACO1}	Array clock to output delay	$C1 = 35 \text{ pF}$		25		30		35	ns
t_{ACH}	Array clock high time	Note (8)	11		14		16		ns
t_{ACL}	Array clock low time	Note (8)	9		11		14		ns
t_{CNT}	Minimum global clock period			20		25		30	ns
f_{CNT}	Max. internal global clock frequency	Note (7)	50		40		33.3		MHz
t_{ACNT}	Minimum array clock period			20		25		30	ns
f_{ACNT}	Max. internal array clock frequency	Note (7)	50		40		33.3		MHz
f_{MAX}	Maximum clock frequency	Note (9)	62.5		50		40		MHz

Internal Timing Parameters Note (10)			EPM5130-1		EPM5130-2		EPM5130		
Symbol	Parameter	Conditions	Min	Max	Min	Max	Min	Max	Unit
t_{IN}	Input pad and buffer delay			5		7		11	ns
t_{IO}	I/O input pad and buffer delay			6		6		11	ns
t_{SEXP}	Expander array delay			12		14		20	ns
t_{LAD}	Logic array delay			12		14		14	ns
t_{LAC}	Logic control array delay			10		12		13	ns
t_{OD}	Output buffer and pad delay	$C1 = 35 \text{ pF}$		5		5		6	ns
t_{ZX}	Output buffer enable delay	$C1 = 35 \text{ pF}$		10		11		13	ns
t_{XZ}	Output buffer disable delay	$C1 = 5 \text{ pF}$		10		11		13	ns
t_{SU}	Register setup time		6		8		12		ns
t_{LATCH}	Flow-through latch delay			3		4		4	ns
t_{RD}	Register delay			1		2		2	ns
t_{COMB}	Combinatorial delay			3		4		4	ns
t_H	Register hold time		4		6		8		ns
t_{IC}	Array clock delay			14		16		16	ns
t_{ICS}	Global clock delay			3		2		1	ns
t_{FD}	Feedback delay			1		1		2	ns
t_{PRE}	Register preset time			5		6		7	ns
t_{CLR}	Register clear time			5		6		7	ns
t_{PIA}	Prog. Interconnect Array delay			14		16		20	ns

Notes to tables:

- (1) Minimum DC input is -0.3 V . During transitions, the inputs may undershoot to -2.0 V or overshoot to 7.0 V for periods shorter than 20 ns under no-load conditions.
- (2) Numbers in brackets are for MIL-STD-883-compliant versions only.
- (3) Numbers in parentheses are for military- and industrial-temperature-range versions, as well as for MIL-STD-883-compliant versions.
- (4) Maximum V_{CC} rise time for the EPM5130/EPM5130A is 200 ms .
- (5) Typical values are for $T_A = 25^\circ\text{C}$ and $V_{CC} = 5\text{ V}$.
- (6) Operating conditions: $V_{CC} = 5\text{ V} \pm 5\%$, $T_A = 0^\circ\text{C}$ to 70°C for commercial use.
 $V_{CC} = 5\text{ V} \pm 10\%$, $T_A = -40^\circ\text{C}$ to 85°C for industrial use.
 $V_{CC} = 5\text{ V} \pm 10\%$, $T_C = -55^\circ\text{C}$ to 125°C for military use.
- (7) Measured with a 16-bit counter programmed into each LAB. I_{CC} measured at 0°C .
- (8) This parameter is measured with a positive-edge-triggered Clock at the register. For negative-edge clocking, the t_{ACH} and t_{ACL} parameters must be swapped.
- (9) The f_{MAX} values represent the highest frequency for pipelined data.
- (10) For information on internal timing parameters, refer to *Application Brief 100 (Understanding Classic, MAX 5000 & MAX 7000 Timing)* in this data book.

Pin-Out Information

Tables 6 and 7 provide pin-out information for the EPM5130.

Table 6. EPM5130 Dedicated Pin-Outs

Dedicated Pin	84-Pin J-Lead	100-Pin PGA	100-Pin QFP
INPUT/CLK	1	C7	16
INPUT	2, 5, 6, 7, 36, 37, 38, 41, 42, 43, 44, 47, 48, 49, 78, 79, 80, 83, 84	A5, A7, A8, A9, A10, B5, B7, B9, C6, L7, L8, M5, M7, M9, N4, N5, N6, N7, N9	9, 10, 11, 14, 15, 16, 17, 20, 21, 22, 59, 60, 61, 64, 65, 66, 67, 70, 71, 72
GND	19, 20, 39, 40, 61, 62, 81, 82	B8, C8, F2, F3, H11, H12, L6, M6	12, 13, 37, 38, 62, 63, 87, 88
VCC	3, 4, 23, 24, 45, 46, 65, 66	A6, B6, F12, F13, H1, H2, M8, N8	18, 19, 43, 44, 68, 69, 93, 94

Table 7. EPM5130 I/O Pin-Outs (Part 1 of 2)

MC	LAB	84-Pin J-Lead	100-Pin PGA	100-Pin QFP	MC	LAB	84-Pin J-Lead	100-Pin PGA	100-Pin QFP
1	A	8	B13	1	17	B	14	A4	23
2	A	9	C12	2	18	B	15	B4	24
3	A	10	A13	3	19	B	16	A3	25
4	A	11	B12	4	20	B	17	A2	26
5	A	12	A12	5	21	B	18	B3	27
6	A	13	B11	6	22	B	21	A1	28
7	A	—	A11	7	23	B	—	B2	29
8	A	—	B10	8	24	B	—	B1	30
9	A	—	—	—	25	B	—	—	—
10	A	—	—	—	26	B	—	—	—
11	A	—	—	—	27	B	—	—	—
12	A	—	—	—	28	B	—	—	—
13	A	—	—	—	29	B	—	—	—
14	A	—	—	—	30	B	—	—	—
15	A	—	—	—	31	B	—	—	—
16	A	—	—	—	32	B	—	—	—
33	C	22	C2	31	49	D	30	G3	41
34	C	25	C1	32	50	D	31	G1	42
35	C	26	D2	33	51	D	32	H3	45
36	C	27	D1	34	52	D	33	J1	46
37	C	28	E2	35	53	D	34	J2	47
38	C	29	E1	36	54	D	35	K1	48
39	C	—	F1	39	55	D	—	K2	49
40	C	—	G2	40	56	D	—	L1	50
41	C	—	—	—	57	D	—	—	—
42	C	—	—	—	58	D	—	—	—
43	C	—	—	—	59	D	—	—	—
44	C	—	—	—	60	D	—	—	—
45	C	—	—	—	61	D	—	—	—
46	C	—	—	—	62	D	—	—	—
47	C	—	—	—	63	D	—	—	—
48	C	—	—	—	64	D	—	—	—

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Table 7. EPM5130 I/O Pin-Outs (Part 2 of 2)

MC	LAB	84-Pin J-Lead	100-Pin PGA	100-Pin QFP	MC	LAB	84-Pin J-Lead	100-Pin PGA	100-Pin QFP
65	E	50	M1	51	81	F	56	N10	73
66	E	51	L2	52	82	F	57	M10	74
67	E	52	N1	53	83	F	58	N11	75
68	E	53	M2	54	84	F	59	N12	76
69	E	54	N2	55	85	F	60	M11	77
70	E	55	M3	56	86	F	63	N13	78
71	E	—	N3	57	87	F	—	M12	79
72	E	—	M4	58	88	F	—	M13	80
73	E	—	—	—	89	F	—	—	—
74	E	—	—	—	90	F	—	—	—
75	E	—	—	—	91	F	—	—	—
76	E	—	—	—	92	F	—	—	—
77	E	—	—	—	93	F	—	—	—
78	E	—	—	—	94	F	—	—	—
79	E	—	—	—	95	F	—	—	—
80	E	—	—	—	96	F	—	—	—
97	G	64	L12	81	113	H	72	G11	91
98	G	67	L13	82	114	H	73	G13	92
99	G	68	K12	83	115	H	74	F11	95
100	G	69	K13	84	116	H	75	E13	96
101	G	70	J12	85	117	H	76	E12	97
102	G	71	J13	86	118	H	77	D13	98
103	G	—	H13	89	119	H	—	D12	99
104	G	—	G12	90	120	H	—	C13	100
105	G	—	—	—	121	H	—	—	—
106	G	—	—	—	122	H	—	—	—
107	G	—	—	—	123	H	—	—	—
108	G	—	—	—	124	H	—	—	—
109	G	—	—	—	125	H	—	—	—
110	G	—	—	—	126	H	—	—	—
111	G	—	—	—	127	H	—	—	—
112	G	—	—	—	128	H	—	—	—